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#### What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

#### Details

Product Status	Active
Core Processor	8051
Core Size	8-Bit
Speed	50MHz
Connectivity	EBI/EMI, I <sup>2</sup> C, LINbus, SPI, UART/USART, USB
Peripherals	CapSense, DMA, LCD, POR, PWM, WDT
Number of I/O	25
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	1K x 8
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 5.5V
Data Converters	A/D 16x12b; D/A 1x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-BSSOP (0.295", 7.50mm Width)
Supplier Device Package	48-SSOP
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/cy8c3245pvi-150t

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



# **More Information**

Cypress provides a wealth of data at www.cypress.com to help you to select the right PSoC device for your design, and to help you to quickly and effectively integrate the device into your design. For a comprehensive list of resources, see the knowledge base article KBA86521, How to Design with PSoC 3, PSoC 4, and PSoC 5LP. Following is an abbreviated list for PSoC 3:

- Overview: PSoC Portfolio, PSoC Roadmap
- Product Selectors: PSoC 1, PSoC 3, PSoC 4, PSoC 5LP In addition, PSoC Creator includes a device selection tool.
- Application notes: Cypress offers a large number of PSoC application notes and code examples covering a broad range of topics, from basic to advanced level. Recommended application notes for getting started with PSoC 3 are:
  - AN54181: Getting Started With PSoC 3
  - AN61290: Hardware Design Considerations
  - AN57821: Mixed Signal Circuit Board Layout
- AN58304: Pin Selection for Analog Designs
- AN81623: Digital Design Best Practices
- AN73854: Introduction To Bootloaders

using the PSoC Creator IDE C compiler

- Development Kits:
  - CY8CKIT-030 is designed for analog performance, for developing high-precision analog, low-power, and low-voltage applications.
  - CY8CKIT-001 provides a common development platform for any one of the PSoC 1, PSoC 3, PSoC 4, or PSoC 5LP families of devices.
  - The MiniProg3 device provides an interface for flash programming and debug.
- Technical Reference Manuals (TRM)
  - Architecture TRM
  - Registers TRM
  - Programming Specification

# PSoC Creator

PSoC Creator is a free Windows-based Integrated Design Environment (IDE). It enables concurrent hardware and firmware design of PSoC 3, PSoC 4, and PSoC 5LP based systems. Create designs using classic, familiar schematic capture supported by over 100 pre-verified, production-ready PSoC Components; see the list of component datasheets. With PSoC Creator, you can:

1. Drag and drop component icons to build your hardware system design in the main design workspace

2. Codesign your application firmware with the PSoC hardware,

- 3. Configure components using the configuration tools
- 4. Explore the library of 100+ components
- 5. Review component datasheets





In addition to the flexibility of the UDB array, PSoC also provides configurable digital blocks targeted at specific functions. For the CY8C32 family these blocks can include four 16-bit timers, counters, and PWM blocks; I<sup>2</sup>C slave, master, and multimaster; and FS USB.

For more details on the peripherals see the "Example Peripherals" section on page 45 of this datasheet. For information on UDBs, DSI, and other digital blocks, see the "Digital Subsystem" section on page 45 of this datasheet.

PSoC's analog subsystem is the second half of its unique configurability. All analog performance is based on a highly accurate absolute voltage reference with less than 1-percent error over temperature and voltage. The configurable analog subsystem includes:

- Analog muxes
- Comparators
- Voltage references
- ADC
- DAC

All GPIO pins can route analog signals into and out of the device using the internal analog bus. This allows the device to interface up to 62 discrete analog signals. The heart of the analog subsystem is a fast, accurate, configurable delta-sigma ADC with these features:

- Less than 100 µV offset
- A gain error of 0.2 percent
- INL less than ±1 LSB
- DNL less than ±1 LSB
- SINAD better than 66 dB

This converter addresses a wide variety of precision analog applications, including some of the most demanding sensors.

A high-speed voltage or current DAC supports 8-bit output signals at an update rate of 8 Msps in current DAC (IDAC) and 1 Msps in voltage DAC (VDAC). It can be routed out of any GPIO pin. You can create higher resolution voltage PWM DAC outputs using the UDB array. This can be used to create a pulse width modulated (PWM) DAC of up to 10 bits, at up to 48 kHz. The digital DACs in each UDB support PWM, PRS, or delta-sigma algorithms with programmable widths.

In addition to the ADC and DAC, the analog subsystem provides multiple comparators.

See the "Analog Subsystem" section on page 55 of this datasheet for more details.

PSoC's 8051 CPU subsystem is built around a single cycle pipelined 8051 8-bit processor running at up to 50 MHz. The CPU subsystem includes a programmable nested vector interrupt controller, DMA controller, and RAM. PSoC's nested vector interrupt controller provides low latency by allowing the CPU to vector directly to the first address of the interrupt service routine, bypassing the jump instruction required by other architectures. The DMA controller enables peripherals to exchange data without CPU involvement. This allows the CPU to run slower (saving power) or use those CPU cycles to improve the performance of firmware algorithms. The single cycle 8051 CPU runs ten times faster than a standard 8051 processor. The processor speed itself is configurable, allowing you to tune active power consumption for specific applications.

PSoC's nonvolatile subsystem consists of flash, byte-writeable EEPROM, and nonvolatile configuration options. It provides up to 64 KB of on-chip flash. The CPU can reprogram individual blocks of flash, enabling bootloaders. You can enable an ECC for high reliability applications. A powerful and flexible protection model secures the user's sensitive information, allowing selective memory block locking for read and write protection. Up to 2 KB of byte-writeable EEPROM is available on-chip to store application data. Additionally, selected configuration options such as boot speed and pin drive mode are stored in nonvolatile memory. This allows settings to activate immediately after POR.

The three types of PSoC I/O are extremely flexible. All I/Os have many drive modes that are set at POR. PSoC also provides up to four I/O voltage domains through the VDDIO pins. Every GPIO has analog I/O, LCD drive<sup>[3]</sup>, CapSense<sup>[4]</sup>, flexible interrupt generation, slew rate control, and digital I/O capability. The SIOs on PSoC allow Voh to be set independently of VDDIO when used as outputs. When SIOs are in input mode they are high impedance. This is true even when the device is not powered or when the pin voltage goes above the supply voltage. This makes the SIO ideally suited for use on an I<sup>2</sup>C bus where the PSoC may not be powered when other devices on the bus are. The SIO pins also have high current sink capability for applications such as LED drives. The programmable input threshold feature of the SIO can be used to make the SIO function as a general purpose analog comparator. For devices with FS USB the USB physical interface is also provided (USBIO). When not using USB these pins may also be used for limited digital functionality and device programming. All of the features of the PSoC I/Os are covered in detail in the "I/O System and Routing" section on page 37 of this datasheet.

The PSoC device incorporates flexible internal clock generators, designed for high stability and factory trimmed for high accuracy. The Internal Main Oscillator (IMO) is the clock base for the system, and has 2-percent accuracy at 3 MHz. The IMO can be configured to run from 3 MHz up to 24 MHz. Multiple clock derivatives can be generated from the main clock frequency to meet application needs. The device provides a PLL to generate clock frequencies up to 50 MHz from the IMO, external crystal, or external reference clock. It also contains a separate, very low-power Internal Low-Speed Oscillator (ILO) for the sleep and watchdog timers. A 32.768-kHz external watch crystal is also supported for use in RTC applications. The clocks, together with programmable clock dividers, provide the flexibility to integrate most timing requirements.

The CY8C32 family supports a wide supply operating range from 1.71 V to 5.5 V. This allows operation from regulated supplies such as  $1.8 \pm 5$  percent,  $2.5 V \pm 10$  percent,  $3.3 V \pm 10$  percent, or  $5.0 V \pm 10$  percent, or directly from a wide range of battery types. In addition, it provides an integrated high efficiency synchronous boost converter that can power the device from supply voltages as low as 0.5 V.

3. This feature on select devices only. See Ordering Information on page 111 for details.

Notes

<sup>4.</sup> GPIOs with opamp outputs are not recommended for use with CapSense.





This enables the device to be powered directly from a single battery or solar cell. In addition, you can use the boost converter to generate other voltages required by the device, such as a 3.3-V supply for LCD glass drive. The boost's output is available on the  $V_{BOOST}$  pin, allowing other devices in the application to be powered from the PSoC.

PSoC supports a wide range of low-power modes. These include a 200-nA hibernate mode with RAM retention and a  $1-\mu$ A sleep mode with RTC. In the second mode the optional 32.768-kHz watch crystal runs continuously and maintains an accurate RTC.

Power to all major functional blocks, including the programmable digital and analog peripherals, can be controlled independently by firmware. This allows low-power background processing when some peripherals are not in use. This, in turn, provides a total device current of only 1.2 mA when the CPU is running at 6 MHz, or 0.8 mA running at 3 MHz.

The details of the PSoC power modes are covered in the "Power System" section on page 31 of this datasheet.

PSoC uses JTAG (4-wire) or SWD (2-wire) interfaces for programming, debug, and test. The 1-wire SWV may also be used for "printf" style debugging. By combining SWD and SWV, you can implement a full debugging interface with just three pins. Using these standard interfaces enables you to debug or program the PSoC with a variety of hardware solutions from Cypress or third party vendors. PSoC supports on-chip break points and 4-KB instruction and data race memory for debug. Details of the programming, test, and debugging interfaces are discussed in the "Programming, Debug Interfaces, Resources" section on page 62 of this datasheet.

# 2. Pinouts

Each VDDIO pin powers a specific set of I/O pins. (The USBIOs are powered from VDDD.) Using the VDDIO pins, a single PSoC can support multiple voltage levels, reducing the need for off-chip level shifters. The black lines drawn on the pinout diagrams in Figure 2-3 through Figure 2-6, as well as Table 2-1, show the pins that are powered by each VDDIO.

Each VDDIO may source up to 100 mA total to its associated I/O pins, as shown in Figure 2-1.

#### Figure 2-1. VDDIO Current Limit



Conversely, for the 100-pin and 68-pin devices, the set of I/O pins associated with any VDDIO may sink up to 100 mA total, as shown in Figure 2-2.

#### Figure 2-2. I/O Pins Current Limit



For the 48-pin devices, the set of I/O pins associated with VDDIO0 plus VDDIO2 may sink up to 100 mA total. The set of I/O pins associated with VDDIO1 plus VDDIO3 may sink up to a total of 100 mA.



#### 4.3.1.3 Data Transfer Instructions

The data transfer instructions are of three types: the core RAM, xdata RAM, and the lookup tables. The core RAM transfer includes transfer between any two core RAM locations or SFRs. These instructions can use direct, indirect, register, and immediate addressing. The xdata RAM transfer includes only the transfer between the accumulator and the xdata RAM location. It can use only indirect addressing. The lookup tables involve nothing but the read of program memory using the Indexed

addressing mode. Table 4-3 lists the various data transfer instructions available.

#### 4.3.1.4 Boolean Instructions

The 8051 core has a separate bit-addressable memory location. It has 128 bits of bit addressable RAM and a set of SFRs that are bit addressable. The instruction set includes the whole menu of bit operations such as move, set, clear, toggle, OR, and AND instructions and the conditional jump instructions. Table 4-4 on page 17Table 4-4 lists the available Boolean instructions.

Mnemonic	Description	Bytes	Cycles
MOV A,Rn	Move register to accumulator	1	1
MOV A,Direct	Move direct byte to accumulator	2	2
MOV A,@Ri	Move indirect RAM to accumulator	1	2
MOV A,#data	Move immediate data to accumulator	2	2
MOV Rn,A	Move accumulator to register	1	1
MOV Rn,Direct	Move direct byte to register	2	3
MOV Rn, #data	Move immediate data to register	2	2
MOV Direct, A	Move accumulator to direct byte	2	2
MOV Direct, Rn	Move register to direct byte	2	2
MOV Direct, Direct	Move direct byte to direct byte	3	3
MOV Direct, @Ri	Move indirect RAM to direct byte	2	3
MOV Direct, #data	Move immediate data to direct byte	3	3
MOV @Ri, A	Move accumulator to indirect RAM	1	2
MOV @Ri, Direct	Move direct byte to indirect RAM	2	3
MOV @Ri, #data	Move immediate data to indirect RAM	2	2
MOV DPTR, #data16	Load data pointer with 16-bit constant	3	3
MOVC A, @A+DPTR	Move code byte relative to DPTR to accumulator	1	5
MOVC A, @A + PC	Move code byte relative to PC to accumulator	1	4
MOVX A,@Ri	Move external RAM (8-bit) to accumulator	1	4
MOVX A, @DPTR	Move external RAM (16-bit) to accumulator	1	3
MOVX @Ri, A	Move accumulator to external RAM (8-bit)	1	5
MOVX @DPTR, A	Move accumulator to external RAM (16-bit)	1	4
PUSH Direct	Push direct byte onto stack	2	3
POP Direct	Pop direct byte from stack	2	2
XCH A, Rn	Exchange register with accumulator	1	2
XCH A, Direct	Exchange direct byte with accumulator	2	3
XCH A, @Ri	Exchange indirect RAM with accumulator	1	3
XCHD A, @Ri	Exchange low order indirect digit RAM with accumulator	1	3

#### Table 4-3. Data Transfer Instructions





#### 4.4.2 DMA Features

- 24 DMA channels
- Each channel has one or more transaction descriptors (TDs) to configure channel behavior. Up to 128 total TDs can be defined
- TDs can be dynamically updated
- Eight levels of priority per channel
- Any digitally routable signal, the CPU, or another DMA channel, can trigger a transaction
- Each channel can generate up to two interrupts per transfer
- Transactions can be stalled or canceled
- Supports transaction size of infinite or 1 to 64k bytes
- TDs may be nested and/or chained for complex transactions

#### 4.4.3 Priority Levels

The CPU always has higher priority than the DMA controller when their accesses require the same bus resources. Due to the system architecture, the CPU can never starve the DMA. DMA channels of higher priority (lower priority number) may interrupt current DMA transfers. In the case of an interrupt, the current transfer is allowed to complete its current transaction. To ensure latency limits when multiple DMA accesses are requested simultaneously, a fairness algorithm guarantees an interleaved minimum percentage of bus bandwidth for priority levels 2 through 7. Priority levels 0 and 1 do not take part in the fairness algorithm and may use 100 percent of the bus bandwidth. If a tie occurs on two DMA requests of the same priority level, a simple round robin method is used to evenly share the allocated bandwidth. The round robin allocation can be disabled for each DMA channel, allowing it to always be at the head of the line. Priority levels 2 to 7 are guaranteed the minimum bus bandwidth shown in Table 4-7 after the CPU and DMA priority levels 0 and 1 have satisfied their requirements.



#### 4.4.4.2 Auto Repeat DMA

Auto repeat DMA is typically used when a static pattern is repetitively read from system memory and written to a peripheral. This is done with a single TD that chains to itself.

#### 4.4.4.3 Ping Pong DMA

A ping pong DMA case uses double buffering to allow one buffer to be filled by one client while another client is consuming the

#### Table 4-7. Priority Levels

Priority Level	% Bus Bandwidth
0	100.0
1	100.0
2	50.0
3	25.0
4	12.5
5	6.2
6	3.1
7	1.5

When the fairness algorithm is disabled, DMA access is granted based solely on the priority level; no bus bandwidth guarantees are made.

#### 4.4.4 Transaction Modes Supported

The flexible configuration of each DMA channel and the ability to chain multiple channels allow the creation of both simple and complex use cases. General use cases include, but are not limited to:

#### 4.4.4.1 Simple DMA

In a simple DMA case, a single TD transfers data between a source and sink (peripherals or memory location). The basic timing diagrams of DMA read and write cycles are shown in Figure 4-1. For more description on other transfer modes, refer to the Technical Reference Manual.

#### Figure 4-1. DMA Timing Diagram



data previously received in the other buffer. In its simplest form, this is done by chaining two TDs together so that each TD calls the opposite TD when complete.

#### 4.4.4.4 Circular DMA

Circular DMA is similar to ping pong DMA except it contains more than two buffers. In this case there are multiple TDs; after the last TD is complete it chains back to the first TD.





#### Figure 4-2. Interrupt Processing Timing Diagram

#### Notes

- 1: Interrupt triggered asynchronous to the clock
- 2: The PEND bit is set on next active clock edge to indicate the interrupt arrival
- 3: POST bit is set following the PEND bit
- 4: Interrupt request and the interrupt number sent to CPU core after evaluation priority (Takes 3 clocks)
- 5: ISR address is posted to CPU core for branching
- 6: CPU acknowledges the interrupt request
- 7: ISR address is read by CPU for branching
- 8, 9: PEND and POST bits are cleared respectively after receiving the IRA from core
- 10: IRA bit is cleared after completing the current instruction and starting the instruction execution from ISR location (Takes 7 cycles)
- 11: IRC is set to indicate the completion of ISR, Active int. status is restored with previous status

#### The total interrupt latency (ISR execution)

- = POST + PEND + IRQ + IRA + Completing current instruction and branching
- = 1+1+1+2+7 cycles
- = 12 cycles



#### Figure 4-3. Interrupt Structure





#### Table 6-1. Oscillator Summary

Source	Fmin	Tolerance at Fmin	Fmax	Tolerance at Fmax	Startup Time
IMO	3 MHz	±2% over voltage and temperature	24 MHz	±4%	13-µs max
MHzECO	4 MHz	Crystal dependent	25 MHz	Crystal dependent	5 ms typ, max is crystal dependent
DSI	0 MHz	Input dependent	33 MHz	Input dependent	Input dependent
PLL	24 MHz	Input dependent	50 MHz	Input dependent	250 µs max
Doubler	48 MHz	Input dependent	48 MHz	Input dependent	1 µs max
ILO	1 kHz	-50%, +100%	100 kHz	-55%, +100%	15 ms max in lowest power mode
kHzECO	32 kHz	Crystal dependent	32 kHz	Crystal dependent	500 ms typ, max is crystal dependent



Figure 6-1. Clocking Subsystem



#### 8.3.2 LUT

The CY8C32 family of devices contains four LUTs. The LUT is a two input, one output lookup table that is driven by any one or two of the comparators in the chip. The output of any LUT is routed to the digital system interface of the UDB array. From the digital system interface of the UDB array, these signals can be connected to UDBs, DMA controller, I/O, or the interrupt controller.

The LUT control word written to a register sets the logic function on the output. The available LUT functions and the associated control word is shown in Table 8-2.

Table 8-2.	LUT Function	vs. Program	Word and	Inputs
		tor i rogram		mpato

Control Word	Output (A and B are LUT inputs)
0000b	<b>FALSE</b> ('0')
0001b	A AND B
0010b	A AND (NOT B)
0011b	A
0100b	(NOT <b>A</b> ) AND <b>B</b>
0101b	В
0110b	A XOR B
0111b	A OR B
1000b	A NOR B
1001b	A XNOR B
1010b	NOT <b>B</b>
1011b	A OR (NOT B)
1100b	NOT A
1101b	(NOT <b>A</b> ) OR <b>B</b>
1110b	A NAND B
1111b	<b>TRUE</b> ('1')

# 8.4 LCD Direct Drive

The PSoC Liquid Crystal Display (LCD) driver system is a highly configurable peripheral designed to allow PSoC to directly drive a broad range of LCD glass. All voltages are generated on chip, eliminating the need for external components. With a high multiplex ratio of up to 1/16, the CY8C32 family LCD driver system can drive a maximum of 736 segments. The PSoC LCD driver module was also designed with the conservative power budget of portable devices in mind, enabling different LCD drive modes and power down modes to conserve power.

PSoC Creator provides an LCD segment drive component. The component wizard provides easy and flexible configuration of LCD resources. You can specify pins for segments and commons along with other options. The software configures the device to meet the required specifications. This is possible because of the programmability inherent to PSoC devices.

Key features of the PSoC LCD segment system are:

- LCD panel direct driving
- Type A (standard) and Type B (low-power) waveform support
- Wide operating voltage range support (2 V to 5 V) for LCD panels

- Static, 1/2, 1/3, 1/4, 1/5 bias voltage levels
- Internal bias voltage generation through internal resistor ladder
- Up to 62 total common and segment outputs
- Up to 1/16 multiplex for a maximum of 16 backplane/common outputs
- Up to 62 front plane/segment outputs for direct drive
- Drives up to 736 total segments (16 backplane × 46 front plane)
- Up to 64 levels of software controlled contrast
- Ability to move display data from memory buffer to LCD driver through DMA (without CPU intervention)
- Adjustable LCD refresh rate from 10 Hz to 150 Hz
- Ability to invert LCD display for negative image
- Three LCD driver drive modes, allowing power optimization

#### Figure 8-6. LCD System



#### 8.4.1 LCD Segment Pin Driver

Each GPIO pin contains an LCD driver circuit. The LCD driver buffers the appropriate output of the LCD DAC to directly drive the glass of the LCD. A register setting determines whether the pin is a common or segment. The pin's LCD driver then selects one of the six bias voltages to drive the I/O pin, as appropriate for the display data.

#### 8.4.2 Display Data Flow

The LCD segment driver system reads display data and generates the proper output voltages to the LCD glass to produce the desired image. Display data resides in a memory buffer in the system SRAM. Each time you need to change the common and segment driver voltages, the next set of pixel data moves from the memory buffer into the Port Data Registers via DMA.

#### 8.4.3 UDB and LCD Segment Control

A UDB is configured to generate the global LCD control signals and clocking. This set of signals is routed to each LCD pin driver through a set of dedicated LCD global routing channels. In addition to generating the global LCD control signals, the UDB also produces a DMA request to initiate the transfer of the next frame of LCD data.







### Figure 9-1. JTAG Interface Connections between PSoC 3 and Programmer



# Table 11-3. AC Specifications<sup>[30]</sup>

Parameter	Description	Conditions	Min	Тур	Max	Units
F <sub>CPU</sub>	CPU frequency	$1.71~V \le V_{DDD} \le 5.5~V$	DC	-	50.01	MHz
F <sub>BUSCLK</sub>	Bus frequency	$1.71~V \le V_{DDD} \le 5.5~V$	DC	_	50.01	MHz
Svdd	V <sub>DD</sub> ramp rate		-	-	0.066	V/µs
T <sub>IO_INIT</sub>	Time from $V_{DDD}/V_{DDA}/V_{CCD}/V_{CCA} \ge$ IPOR to I/O ports set to their reset states		-	-	10	μs
T <sub>STARTUP</sub>	Time from $V_{DDD}/V_{DDA}/V_{CCD}/V_{CCA} \ge PRES$ to CPU executing code at reset vector	$V_{CCA}/V_{CCD}$ = regulated from $V_{DDA}/V_{DDD}$ , no PLL used, IMO boot mode (12 MHz typ.)	-	-	74	μs
T <sub>SLEEP</sub>	Wakeup from sleep mode – Application of non-LVD interrupt to beginning of execution of next CPU instruction		-	-	15	μs
T <sub>HIBERNATE</sub>	Wakeup from hibernate mode – Application of external interrupt to beginning of execution of next CPU instruction		-	_	100	μs

Figure 11-4. F<sub>CPU</sub> vs. V<sub>DD</sub>



Note 30. Based on device characterization (Not production tested).



Figure 11-17. SIO Output High Voltage and Current, Unregulated Mode



Figure 11-19. SIO Output High Voltage and Current, Regulated Mode



Table 11-12. SIO AC Specifications

Parameter	Description	Conditions	Min	Тур	Max	Units
TriseF	Rise time in Fast Strong Mode (90/10%) <sup>[41]</sup>	Cload = 25 pF, V <sub>DDIO</sub> = 3.3 V	-	_	12	ns
TfallF	Fall time in Fast Strong Mode (90/10%) <sup>[41]</sup>	Cload = 25 pF, $V_{DDIO}$ = 3.3 V	-	-	12	ns
TriseS	Rise time in Slow Strong Mode (90/10%) <sup>[41]</sup>	Cload = 25 pF, $V_{DDIO}$ = 3.0 V	_	_	75	ns
TfallS	Fall time in Slow Strong Mode (90/10%) <sup>[41]</sup>	Cload = 25 pF, $V_{DDIO}$ = 3.0 V	-	-	60	ns



# Figure 11-18. SIO Output Low Voltage and Current, Unregulated Mode



Figure 11-22. USBIO Output High Voltage and Current, GPIO Mode







#### Table 11-15. USBIO AC Specifications

Parameter	Description	Conditions	Min	Тур	Max	Units
Tdrate	Full-speed data rate average bit rate		12 – 0.25%	12	12 + 0.25%	MHz
Tjr1	Receiver data jitter tolerance to next transition		-8	-	8	ns
Tjr2	Receiver data jitter tolerance to pair transition		-5	_	5	ns
Tdj1	Driver differential jitter to next transition		-3.5	-	3.5	ns
Tdj2	Driver differential jitter to pair transition		-4	-	4	ns
Tfdeop	Source jitter for differential transition to SE0 transition		-2	-	5	ns
Tfeopt	Source SE0 interval of EOP		160	-	175	ns
Tfeopr	Receiver SE0 interval of EOP		82	_	_	ns
Tfst	Width of SE0 interval during differ- ential transition		-	-	14	ns
Fgpio_out	GPIO mode output operating	$3 \text{ V} \leq \text{V}_{\text{DDD}} \leq 5.5 \text{ V}$	-	_	20	MHz
	frequency	V <sub>DDD</sub> = 1.71 V	-	_	6	MHz
Tr_gpio	Rise time, GPIO mode, 10%/90%	V <sub>DDD</sub> > 3 V, 25 pF load	_	-	12	ns
	V <sub>DDD</sub>	V <sub>DDD</sub> = 1.71 V, 25 pF load	_	-	40	ns
Tf_gpio	Fall time, GPIO mode, 90%/10% V <sub>DDD</sub>	V <sub>DDD</sub> > 3 V, 25 pF load	_	_	12	ns
		V <sub>DDD</sub> = 1.71 V, 25 pF load	_	_	40	ns

Figure 11-24. USBIO Output Rise and Fall Times, GPIO Mode,



V<sub>DDD</sub> = 3.3 V, 25 pF Load



Table 11-16. USB Driver AC Specifications

Parameter	Description	Conditions	Min	Тур	Max	Units
Tr	Transition rise time		_	-	20	ns
Tf	Transition fall time		_	-	20	ns
TR	Rise/fall time matching	V <sub>USB_5</sub> , V <sub>USB_3.3</sub> , see USB DC Specifications on page 98	90%	_	111%	
Vcrs	Output signal crossover voltage		1.3	-	2	V

# 11.4.4 XRES

#### Table 11-17. XRES DC Specifications

Parameter	Description	Conditions	Min	Тур	Max	Units
V <sub>IH</sub>	Input voltage high threshold		$0.7 \times V_{DDIO}$	-	-	V
V <sub>IL</sub>	Input voltage low threshold		-	-	0.3 ×	V
					V <sub>DDIO</sub>	
Rpullup	Pull-up resistor		3.5	5.6	8.5	kΩ
C <sub>IN</sub>	Input capacitance <sup>[43]</sup>		-	3	-	pF
V <sub>H</sub>	Input voltage hysteresis (Schmitt-Trigger) <sup>[43]</sup>		-	100	_	mV
Idiode	Current through protection diode to $V_{DDIO}$ and $V_{SSIO}$		-	Ι	100	μA

# Table 11-18. XRES AC Specifications

Parameter	Description	Conditions	Min	Тур	Max	Units
T <sub>RESET</sub>	Reset pulse width		1	-	-	μs



Figure 11-28. IDAC DNL vs Input Code, Range = 255  $\mu\text{A},$  Source Mode



Figure 11-30. IDAC INL vs Temperature, Range = 255  $\mu A,$  High speed mode



Figure 11-29. IDAC DNL vs Input Code, Range = 255  $\mu\text{A},$  Sink Mode



Figure 11-31. IDAC DNL vs Temperature, Range = 255  $\mu\text{A},$  High speed mode







# 11.5.6 Voltage Digital to Analog Converter (VDAC)

See the VDAC component datasheet in PSoC Creator for full electrical specifications and APIs.

Unless otherwise specified, all charts and graphs show typical values.

# Table 11-28. VDAC DC Specifications

Parameter	Description	Conditions	Min	Тур	Max	Units
	Resolution		-	8	-	bits
INL1	Integral nonlinearity	1 V scale	-	±2.1	±2.5	LSB
INL4	Integral nonlinearity <sup>[52]</sup>	4 V scale	-	±2.1	±2.5	LSB
DNL1	Differential nonlinearity	1 V scale	-	±0.3	±1	LSB
DNL4	Differential nonlinearity <sup>[52]</sup>	4 V scale	-	±0.3	±1	LSB
Rout	Output resistance	1 V scale	-	4	-	kΩ
		4 V scale	-	16	-	kΩ
V <sub>OUT</sub>	Output voltage range, code = 255	1 V scale	-	1.02	-	V
		4 V scale, V <sub>DDA</sub> = 5 V	-	4.08	-	V
	Monotonicity		_	-	Yes	-
V <sub>OS</sub>	Zero scale error		_	0	±0.9	LSB
Eg	Gain error	1 V scale	-	-	±2.5	%
		4 V scale	_	-	±2.5	%
TC_Eg	Temperature coefficient, gain error	1 V scale	_	-	0.03	%FSR / °C
		4 V scale	-	-	0.03	%FSR/°C
I <sub>DD</sub>	Operating current	Low speed mode	-	-	100	μA
		High speed mode	_	_	500	μA

# Figure 11-40. VDAC INL vs Input Code, 1 V Mode



# Figure 11-41. VDAC DNL vs Input Code, 1 V Mode



Note 52. Based on device characterization (Not production tested).



# Table 11-29. VDAC AC Specifications t

Parameter	Description	Conditions	Min	Тур	Max	Units
F <sub>DAC</sub>	Update rate	1 V scale	-	-	1000	ksps
		4 V scale	-	-	250	ksps
TsettleP	Settling time to 0.1%, step 25% to 75%	1 V scale, Cload = 15 pF	-	0.45	1	μs
		4 V scale, Cload = 15 pF	-	0.8	3.2	μs
TsettleN	Settling time to 0.1%, step 75% to 25%	1 V scale, Cload = 15 pF	_	0.45	1	μs
		4 V scale, Cload = 15 pF	-	0.7	3	μs
	Voltage noise	Range = 1 V, High speed mode, V <sub>DDA</sub> = 5 V, 10 kHz	1	750	_	nV/sqrtHz

# Figure 11-48. VDAC Step Response, Codes 0x40 - 0xC0, 1 V Mode, High speed mode, $V_{DDA} = 5 V$







Figure 11-49. VDAC Glitch Response, Codes 0x7F - 0x80, 1 V Mode, High speed mode,  $V_{\text{DDA}}$  = 5 V









#### 11.9.4 kHz External Crystal Oscillator

# Table 11-71. kHzECO DC Specifications<sup>[72]</sup>

Parameter	Description	Conditions	Min	Тур	Max	Units
I <sub>CC</sub>	Operating current	Low-power mode; CL = 6 pF	-	0.25	1.0	μA
DL	Drive level		_	_	1	μW

#### Table 11-72. kHzECO AC Specifications

Parameter	Description	Conditions	Min	Тур	Max	Units
F	Frequency		-	32.768	_	kHz
T <sub>ON</sub>	Startup time	High power mode	-	1	_	S

#### 11.9.5 External Clock Reference

# Table 11-73. External Clock Reference AC Specifications<sup>[72]</sup>

Parameter	Description	Conditions	Min	Тур	Max	Units
	External frequency range		0	-	33	MHz
	Input duty cycle range	Measured at V <sub>DDIO</sub> /2	30	50	70	%
	Input edge rate	V <sub>IL</sub> to V <sub>IH</sub>	0.5	_	_	V/ns

#### 11.9.6 Phase–Locked Loop

# Table 11-74. PLL DC Specifications

Parameter	Description	Conditions	Min	Тур	Max	Units
I <sub>DD</sub>	PLL operating current	In = 3 MHz, Out = 24 MHz	_	200	_	μA

#### Table 11-75. PLL AC Specifications

Parameter	Description	Conditions	Min	Тур	Max	Units
Fpllin	PLL input frequency <sup>[73]</sup>		1	_	48	MHz
	PLL intermediate frequency <sup>[74]</sup>	Output of prescaler	1	-	3	MHz
Fpllout	PLL output frequency <sup>[73]</sup>		24	-	50	MHz
	Lock time at startup		-	_	250	μs
Jperiod-rms	Jitter (rms) <sup>[72]</sup>		_	_	250	ps

Notes

72. Based on device characterization (Not production tested).
73. This specification is guaranteed by testing the PLL across the specified range using the IMO as the source for the PLL.
74. PLL input divider, Q, must be set so that the input frequency is divided down to the intermediate frequency range. Value for Q ranges from 1 to 16.



# 12.1 Part Numbering Conventions

PSoC 3 devices follow the part numbering convention described here. All fields are single character alphanumeric (0, 1, 2, ..., 9, A, B, ..., Z) unless stated otherwise.

CY8Cabcdefg-xxx

a: Architecture ■ ef: Package code B 3: PSoC 3 Two character alphanumeric □ 5: PSoC 5 AX: TQFP LT: QFN b: Family group within architecture □ PV: SSOP □ 2: CY8C32 family □ FN: CSP □ 4: CY8C34 family ■ g: Temperature range □ 6: CY8C36 family ■ 8: CY8C38 family C: commercial I: industrial c: Speed grade A: automotive □ 4: 50 MHz xxx: Peripheral set □ 6: 67 MHz D Three character numeric d: Flash capacity D No meaning is associated with these three characters. □ 4: 16 KB 🛛 5: 32 KB **a** 6: 64 KB CY8C 3 2 4 6 P V I - x x x Example Cypress Prefix 3: PSoC 3 Architecture 2: CY8C32 Family Family Group within Architecture 4: 50 MHz Speed Grade -6: 64 KB Flash Capacity -

PV: SSOP Package Code \_\_\_\_\_\_\_

Tape and reel versions of these devices are available and are marked with a "T" at the end of the part number.

All devices in the PSoC 3 CY8C32 family comply to RoHS-6 specifications, demonstrating the commitment by Cypress to lead-free products. Lead (Pb) is an alloying element in solders that has resulted in environmental concerns due to potential toxicity. Cypress uses nickel-palladium-gold (NiPdAu) technology for the majority of leadframe-based packages.

A high level review of the Cypress Pb-free position is available on our website. Specific package information is also available. Package Material Declaration Datasheets (PMDDs) identify all substances contained within Cypress packages. PMDDs also confirm the absence of many banned substances. The information in the PMDDs will help Cypress customers plan for recycling or other "end of life" requirements.



Descript Docume	Description Title: PSoC <sup>®</sup> 3: CY8C32 Family Data Sheet Programmable System-on-Chip (PSoC <sup>®</sup> ) (continued) Document Number: 001-56955							
Revision	ECN	Submission Date	Orig. of Change	Description of Change				
*J	3200146	03/28/2011	MKEA	Removed Preliminary status from the data sheet. Updated JTAG ID Deleted Cin_G1, ADC input capacitance from Delta-Sigma ADC DC spec table Updated JTAG Interface AC Specifications and SWD Interface Specifications tables Updated USBIO DC specs Added 0.01 to max speed Updated Features on page 1 Added Section 5.5, Nonvolatile Latches Updated Flash AC specs Updated delta-sigma graphs, noise histogram figures and RMS Noise spec tables Add reference to application note AN58304 in section 8.1 Updated 100-pin TQFP package spec Added oscillator, I/O, VDAC, regulator graphs Updated JTAG/SWD timing diagrams Updated GPIO and SIO AC specs Updated POR with Brown Out AC spec table Updated IDAC graphs Added DMA timing diagram, interrupt timing and interrupt vector, I2C timing diagrams Added full chip performance graphs Changed MHzECO range. Added "Solder Reflow Peak Temperature" table.				
*К	3259185	05/17/2011	MKEA	Added JTAG and SWD interface connection diagrams Updated $T_{JA}$ and $T_{JC}$ values in Table 13-1 Changed typ and max values for the TCVos parameter in Opamp DC specifications table. Updated Clocking subsystem diagram. Changed VSSD to VSSB in the PSoC Power System diagram Updated Ordering information.				